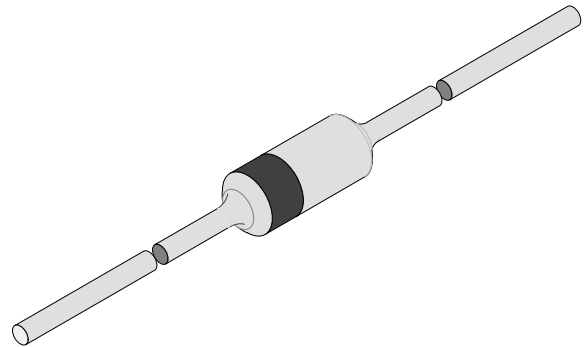


## Silicon Z-Diodes

### Features

- Very sharp reverse characteristic
- Very high stability
- Low reverse current level
- $V_Z$ -tolerance  $\pm 5\%$



94 9367

### Applications

Voltage stabilization

### Absolute Maximum Ratings

 $T_j = 25^\circ\text{C}$ 

Parameter	Test Conditions	Type	Symbol	Value	Unit
Power dissipation	$T_L \leq 75^\circ\text{C}$		$P_V$	500	mW
Z-current			$I_Z$	$P_V/V_Z$	mA
Junction temperature			$T_j$	200	$^\circ\text{C}$
Storage temperature range			$T_{\text{stg}}$	-65...+200	$^\circ\text{C}$

### Maximum Thermal Resistance

 $T_j = 25^\circ\text{C}$ 

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	$l=9.5\text{mm (3/8")}$ , $T_L=\text{constant}$	$R_{\text{thJA}}$	300	K/W

### Electrical Characteristics

 $T_j = 25^\circ\text{C}$ 

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F=200\text{mA}$		$V_F$			1.1	V

# 1N957B...1N963B

Vishay Telefunken



Type	$V_{Znom}^{1)}$	$I_{ZT}$ for $r_{zIT}$		$r_{zik}$ at $I_{ZK}$		$I_R$ at $V_R$		$TK_{VZ}$
	V	mA	$\Omega$	$\Omega$	mA	$\mu A$ max	V	%/K
1N957B	6.8	20	< 4.5	< 700	1.0	150	5.2	< -0.045
1N958B	7.5	20	< 5.5	< 700	0.5	75	5.7	< +0.050
1N959B	8.2	20	< 6.5	< 700	0.5	50	6.2	< +0.058
1N960B	9.1	20	< 7.5	< 700	0.5	25	6.9	< +0.062
1N961B	10	20	< 8.5	< 700	0.25	10	7.6	< +0.065
1N962B	11	20	< 9.5	< 700	0.25	5	8.4	< +0.068
1N963B	12	20	< 11.5	< 700	0.25	5	9.1	< +0.075

1.)Based on dc measurement at thermal equilibrium; lead length = 9.5mm (3/8");  
thermal resistance of heat sink = 30 K/W.

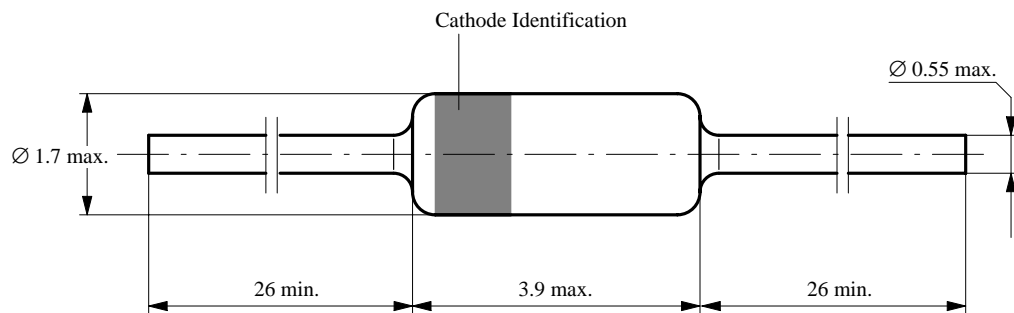
## Dimensions in mm



technical drawings  
according to DIN  
specifications

94 9366

Standard Glass Case  
54 A 2 DIN 41880  
JEDEC DO 35  
Weight max. 0.3g





## Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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